Rev. 3-21-01

## ER OF ATTORNEY FOR U.S. PATENT APPLICATION DECI

(X) PCT () DESIGN () Original () Supplemental () Substitute

As a below named inventor, I hereby declare that: my residence, post office address and citizenship are as stated below next to my name; that I verily believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural inventors are named below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

Title: METHOD AND APPA	RATUS FOR GROWING HIGH QUALITY	SINGLE CRYSTAL	
of which is described and claim	med in:		
) the attached specification, o	r .		
the specification in application Serial No.		, filed, and	with amendments
hrough	. or		
(X) the specification in Interna	tional Application No. PCT/JP00/03264	, filed May 22, 2000, and as amend	ed on
(if applicable).			
I hereby state that I have revie	ewed and understand the content of the abo	ve-identified specification, including	g the claims, as amende
by any amendment(s) referred			
Nicknowledge my duty to disc	close to the Patent and Trademark Office a	ill information known to me to be m	naterial to patentability a
defined in Title 37, Code of F	ederal Regulations, §1.56.		
12.3			
I hereby claim priority benef	fits under Title 35, United States Code,	§119 (and §172 if this application	is for a Design) of an
application(s) for patent or in	ventor's certificate listed below and have:	also identified below any application	n for patent or inventor
certificate having a filing date	before that of the application on which pr	iority is claimed:	•
रेम की			
W.			
COUNTRY	APPLICATION NO.	DATE OF FILING	PRIORITY
er g Suite			CLAIMED
हरा केंद्र -		14 44 4000	1775
If $-$	1999-178815	May 22, 1999	YES
Japan			

I hereby claim the benefit under Title 35, United States Code §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code §112, I acknowledge the duty to disclose information material to patentability as defined in Title 37, Code of Federal Regulations, \$1.56 which occurred between the filling date of the prior application and the national or PCT international filing date of this application:

APPLICATION SERIAL NO.	U.S. FILING DATE	STATUS: PATENTED, PENDING, ABANDONED

And I hereby appoint Michael R. Davis, Reg. No. 25,134; Matthew M. Jacob, Reg. No. 25,154; Warren M. Cheek, Jr., Reg. No. 33,367; Nils Pederson, Reg. No. 33,145; Charles R. Watts, Reg. No. 33,142; and Michael S. Huppert, Reg. No. 40,268, who together constitute the firm of WENDEROTH, LIND & PONACK, L.L.P., as well as any other attorneys and agents associated with Customer No. 000513, to prosecute this application and to transact all business in the U.S. Patent and Trademark Office connected therewith.

I hereby authorize the U.S. attorneys and agents named herein to accept and follow instructions from NISHIZAWA & ASSOCIATES as to any action to be taken in the U.S. Patent and Trademark Office regarding this application without direct communication between the U.S. attorneys and myself. In the event of a change in the persons from whom instructions may be taken, the U.S. attorneys named herein will be so notified by me.

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I further declare that all statements made herein of my own knowledge are true, and that all statements on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

statements may jeopardize the validity of the application or any patent is	same diareon.
1st inventor	Date December 18, 2001
2nd Inventor	Date December 18, 2001
3rd inventor	Date December 18, 2001
Masashi YOSHIMURA 4th Inventor	Date
5th Inventor	_
6th Inventor	Date
The above application may be more particularly identified as follows:  U.S. Application Serial No.	Filing Date November 23, 2001
Applicant Reference Number 00-F-024US/UA Atty Docket No. 200	
File of Invention METHOD AND APPARATUS FOR GROWING I	HIGH QUALITY SINGLE CRYSTAL
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